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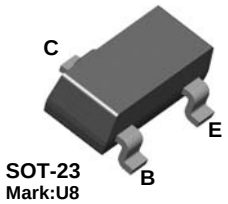
September 2012

BSR14
NPN General Purpose Amplifier

Features

- This device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA.
- Sourced from Process 19.
- See BCW65C for characteristics.



SOT-23
Mark:U8

Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	75	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	800	mA
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Max.	Units
		*BSR14	
P_D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

* Device mounted on FR-4 PCB 40 mm X 40 mm X 1.5 mm.

Electrical Characteristics T_a = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 10μA, I_B = 0	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 10μA, I_E = 0	75		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10μA, I_C = 0	6.0		V
I_{CBO}	Collector-Cutoff Current	V_{CB} = 60V, V_{CB} = 60V, T_a = 150°C		10 10	nA μA
I_{CEX}	Collector-Cutoff Current	V_{CE} = 60V, V_{EB} = 3.0V		10	nA
I_{BEX}	Reverse Base Current	V_{CE} = 60V, V_{EB} = 3.0V		20	nA
I_{EBO}	Emitter-Cutoff Current	V_{EB} = 3.0V, I_C = 0		15	nA
ON CHARACTERISTICS					
h_{FE}	DC Current Gain	I_C = 0.1mA, V_{CE} = 10V I_C = 1.0mA, V_{CE} = 10V I_C = 10mA, V_{CE} = 10V I_C = 150mA, V_{CE} = 10V I_C = 150mA, V_{CE} = 1.0V I_C = 500mA, V_{CE} = 10V	35 50 75 100 50 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = 150mA, I_B = 15mA I_C = 500mA, I_B = 50mA		0.3 1.0	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	I_C = 150mA, I_B = 15mA I_C = 500mA, I_B = 50mA	0.6	1.2 2.0	V V
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 20mA, V_{CE} = 20V, f = 100mHz	300		MHz
C_{CB}	Collector-Base Capacitance	V_{CB} = 10V, I_E = 0, f = 1.0MHz		8.0	pF
h_{ie}	Input Impedance	V_{CE} = 10V, I_C = 1.0mA, f = 1.0kHz	2.0	8.0	kΩ
h_{fe}	Small-Signal Current Gain	V_{CE} = 10V, I_C = 1.0mA, f = 1.0kHz	50	300	
h_{oe}	Output Admittance	V_{CE} = 10V, I_C = 1.0mA, f = 1.0kHz	5	35	μS
SWITCHING CHARACTERISTICS					
t_d	Delay Time	V_{CC} = 30V, $V_{BE(OFF)}$ = 0.5V, I_C = 150mA, I_{B1} = 15mA		10	ns
t_r	Rise Time			25	ns
t_s	Storage Time	V_{CC} = 30V, I_C = 150mA, I_{B1} = I_{B2} = 15mA		225	ns
t_f	Fall Time			60	ns

Spice Model

NPN (Is=14.34f Xti=3 Eg=1.11 Vaf=74.03 Bf=255.9 Ne=1.307 Ise=14.34f Ikf=.2847 Xtb=1.5 Br=6.092 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=7.306p Mjc=.3416 Vjc=.75 Fc=.5 Cje=22.01p Mje=.377 Vje=.75 Tr=46.91n Tf=411.1p Itf=.6 Vtf=1.7 Xtf=3 Rb=10)

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